AMENDMENT & RESPONSE UNDER 37 C.F.R. § 1.116 - EXPEDITED PROCEDURE

Serial Number: 09/649,827 Filing Date: August 29, 2000

itle: METHOD FOR ATTACHING A SEMICONDUCTOR DIE TO A SUBSTRATE

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## **IN THE CLAIMS**

Please substitute the claim set in the appendix entitled Clean Version of Pending Claims for the previously pending claim set. The substitute claim set is intended to reflect amendment of previously pending claims 39 and 44. The specific amendments to individual claims are detailed in the following marked up set of claims.

39.) (Thrice Amended) A method of attaching a semiconductor die to an organic support structure, comprising:

affixing a first side of a two-sided adhesive tape to a surface of the organic support structure, wherein adhesive of the adhesive tape comprises a [pressure sensitive,] <u>hybrid material</u> of thermoplastic and thermosetting adhesive;

elevating the temperature to 100 degrees C to activate the first side of the adhesive tape; applying pressure to the tape and organic support structure to laminate the adhesive tape to the organic support structure;

affixing a face of the semiconductor die to a second side of the adhesive tape; elevating the temperature of the tape to activate the second side of the adhesive tape; and applying pressure to the die and organic support structure to laminate the adhesive tape to the die.

44.) (Thrice Amended) A method of attaching a semiconductor die to an organic support structure, comprising:

affixing a first side of a two-sided adhesive tape to a surface of the organic support structure, wherein adhesive of the adhesive tape comprises a [pressure sensitive,] <u>hybrid material</u> of thermoplastic and thermosetting adhesive;

elevating the temperature of the tape to activate the first side of the adhesive tape; applying pressure to the tape and organic support structure to laminate the adhesive tape

to the organic support structure, wherein elevating the temperature and applying pressure occurs

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for 100ms;

the die;

affixing a face of the semiconductor die to a second side of the adhesive tape; elevating the temperature of the tape to activate the second side of the adhesive tape; applying pressure to the die and organic support structure to laminate the adhesive tape to

wire bonding bond wires to a plurality of bond pads on the die face with a plurality of lead connections on the organic support structure;

applying an encapsulating material over the bond pads, bond wires, lead connections, and a portion of the die face and support structure.

## **REMARKS**

Applicant has carefully reviewed and considered the Office Action mailed on <u>April 9</u>, 2002, and the references cited therewith.

Claims 39 and 44 are amended such that claims 34-63 are now pending in this application.

## Information Disclosure Statement

Applicant respectfully requests that a copy of the 1449 Form, listing all references that were submitted with the Information Disclosure Statement filed on <u>August 29, 2000</u>, marked as being considered and initialed by the Examiner, be returned with the next official communication.

## Objection to the Disclosure

The disclosure was objected to because of the use of the term "thermoset" at page 10, lines 10 and 11. Applicant has amended the specification in accordance with the suggestion made by the Examiner in paragraph 1 of the Office Action. Withdrawal of the objection is respectfully requested.